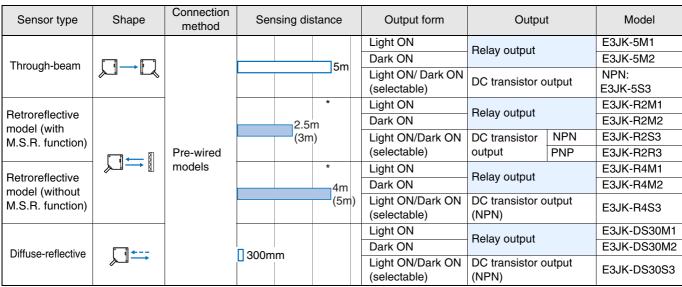
CE

Built-in power supply photoelectric sensor

E3JK

Wide range voltage power supply

Pre-wired type/E3JK Slim body full of functions and economically available



* The value within the parentheses indicates the sensing distance applied when the E39-R2 reflector is used. Note: The UL-listed model ends with "-US". (Example: E3JK-5M1-US). Note that the DC transistor type of the E3JK is UL-unlisted.

Accessories (Order Separately)

Slits

Slit width	Sensing dista	nce	Minimum sensing object (typical)	Model	Quantity	Remarks	
Width 1 mmx20 mm	E3JK-5	0.7 m	1 mm dia.	E39-S39	1 pc. each for emitter and receiver (total 2 pcs.)	(Seal type long slit) Can be used with the through- beam model E3JK-5	

Reflectors

Name	Sensing dist	Model	Quantity	Remarks		
	E3JK-R2	2.5 m (rated value)	E39-R1	1	Attached to the E3JK-R2	
Reflectors	E3JK-R4	4 m (rated value)	E39-N1		Attached to the E3JK-R4 $\Box\Box$.	
nelleciois	E3JK-R2	3 m	E39-R2	1		
	E3JK-R4	5 m	E39-N2			
Small reflector	E3JK-R2	1 m (5 mm) *	E39-R3	1		
	E3JK-R2	750 mm (200 mm) *	E39-RS1		The M.S.R. function is available.	
Tape Reflector	E3JK-R2	1.2 m (200 mm) *	E39-RS2	1		
	E3JK-R2	1.5 m (200 mm) *	E39-RS3			

* Values in parentheses indicate the minimum required distance between the sensor and reflector. Note: When the reflector used is other than the supplied one, set the sensing distance to about 0.7 times of the typical example as a guideline.

Mounting Brackets

Shape	Model	Quantity	Remarks
	E39-L40	1	Supplied with E3JK

Note: If a through-beam model is used, order two Mounting Brackets for the emitter and receiver respectively.

Rating/Performance

E3JK

Sensor type		Through-beam		Retroflective model (with M.S.R. function)		Retroflective model (without M.S.R. function)		Diffuse-reflective		
Item	Model	E3JK-5M	E3JK-5S3	E3JK-R2M□	E3JK-R2□3	E3JK-R4M□	E3JK-R4S3	E3JK-DS30M	E3JK-DS30S3	
Sensing distance		5 m		2.5 m (When using the E39-R1)		4 m (When using the E39-R1)		300 mm (White paper 100x100 mm)		
Standard sensing object		Opaque 14.8	dia. min.	Opaque: 75 n	nm dia. min.					
Differential distance									20% max. of sensing distance	
Directional angle		Both emitter a 3°C to 20°C	and receiver:	1° to 5°						
Light sou (wave le		Infrared LED	(950 nm)	Red LED (66	0 nm)			Infrared LED (950 nm)		
Power s voltage	upply	12 to 240 VD	C ±10% ripple	(p-p) : 10% ma	ax. 24 to 240 V	/AC ±10% 50/6	60 Hz			
Cur-	DC	3 W max.		2 W max.						
rent con- sump- tion	AC	3 W max.		2 W max.						
Control output		Relay output: 250VAC 3 A (cosφ=1) max., 5 VDC 10 mA min.	DC SSR Negative common 48 VDC 100 mA max. Leak current 0.1 mA max. With load short-circuit protection	Relay output: 250VAC 3 A (cosφ=1) max., 5 VDC 10 mA min.	DC SSR Negative or positive common 48 VDC 100 mA max. Leak current 0.1 mA max. With load short-circuit protection	Relay output: 250VAC 3 A (cosφ=1) max., 5 VDC 10 mA min.	DC SSR Negative common 48 VDC 100 mA max. Leak current 0.1 mA max. With load short-circuit protection	Relay output: 250VAC 3 A (cosφ=1) max., 5 VDC 10 mA min.	DC SSR Negative common 48 VDC 100 mA max. Leak current 0.1 mA max. With load short-circuit protection	
Life ex- pect-	ex- chani- 50 million times or more (sw			vitching frequer	ncy 18,000 tim	es/hour)				
ancy (relay output)	Electri- cal	100 thousand times or more (switching frequency 18,000 times/hour)								
Respons	se time	30 ms max.	10 ms max.	30 ms max.	5 ms max.	30 ms max.	5 ms max.	30 ms max.	5 ms max.	
Sensitivi adjustme	ent	Single-turn adjustment							djustment	
Ambient illuminance		Incandescent lamp: 3,000 lux max.								
Ambient temperature		Operating: -25°C to 55°C, Storage: -30°C to 70°C (with no icing or condensation)								
		Operating: 45% to 85%RH, Storage: 35% to 95%RH (with no condensation)								
Insulation resistance		20 M Ω min. at 500 VDC								
Dielectric strength		1,500 VAC at 50/60 Hz for 1 minute								
Vibra- tion resis-	De- struc- tion	10 to 55 Hz, 1.5 mm double amplitude for 2 hours each in X, Y, and Z directions								
tance	Mal									

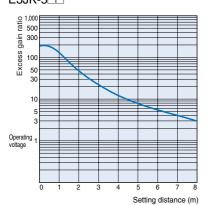
E3JK

	Sensor type Through-beam		Retroflective model (with M.S.R. function)		Retroflective model (without M.S.R. function)		Diffuse-reflective				
Item	Model	E3JK-5M□	E3JK-5S3	E3JK-R2M□	E3JK-R2□3	E3JK-R4M□	E3JK-R4S3	E3JK-DS30M	E3JK-DS30S3		
	De- struc- tion	Destruction: 500 m/s ² for 3 times each in X, Y, and Z directions									
Shock resis- tance	Mal- function	Destruc- tion: 100m/s ² (approx. 10G) 3 times each in X, Y, and Z directions	Destruction: 500 m/s ² for 3 times each in X, Y, and Z directions	Destruction: 100m/s ² (approx. 10G) 3 times each in X, Y, and Z direc tions	Destruction: 500 m/s ² for 3 times each in X, Y and Z directions	Destruction: 100m/s ² (approx. 10G) 3 times each in X, Y, and Z direc tions	Destruction: 500 m/s ² for 3 times each in X, Y, and Z directions	Destruction: 100m/s ² (approx. 10G) 3 times each in X, Y, and Z direc tions			
Protective structure		IEC60529 IP64									
Connect method	Connection method Pre-wired models (standard length: 2 m)										
Weight (Packed state)		Approx. 420 g Approx. 250 g									
	Case	ABS									
Materi- al	Lens	Acrylics									
	Mount- ing bracket	Steel									
Accesso	ries	Mounting bracket (with screws), nuts, instruction manual, reflector (retroreflective model only)									

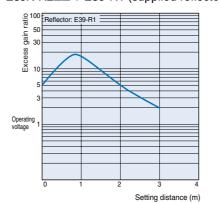
Characteristic data (typical)

Excess Gain Ratio vs. Setting Distance

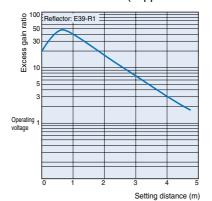
Through-beam model E3JK-5□□



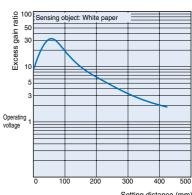
Retroreflective Models E3JK-R2□□ + E39-R1 (supplied reflector)



E3JK-R4 + E39-R1 (supplied reflector)



Diffuse-reflective E3JK-DS30

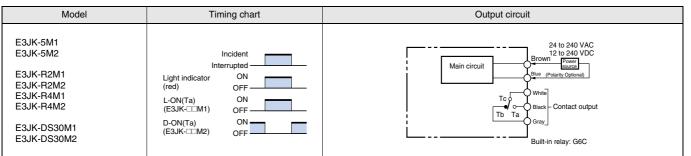


Setting distance (mm)

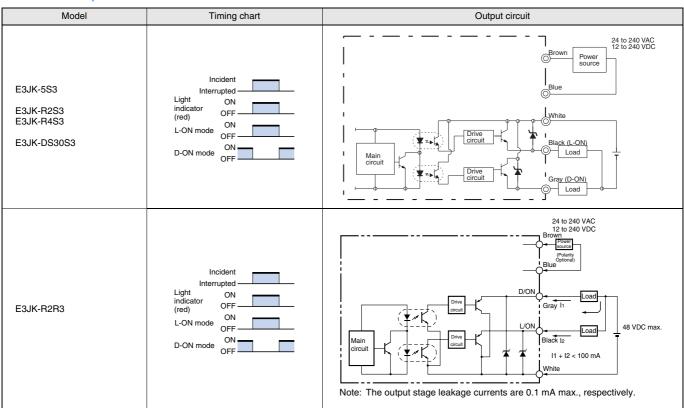
Output Circuit Diagram

E3JK

Relay output



DC transistor output



Note: Connect to brown and blue on the emitter side.

Operation

Adjustment

Item Model	Through-beam	Retroreflective Models	Diffuse-reflective
E3JK	Swing the receiver and emitter ver- tically and/or horizontally and set the adjuster in the center of the range where the indicator of the re- ceiver turns ON.	Like the through-beam model, ad- just the reflector and emitter/re- ceiver. Since the directional angle of the emitter/receiver is 1 to 5°, ad- just the emitter/receiver especially carefully.	With sensing object Without sensing object Without sensing object Setting Sensitivity (1) If you have a sensing object as shown in the figure, turn the sensitivity adjuster clockwise (increase the sensitivity) until the indicator is turned ON, and define this adjuster position as (A). (2) Remove the sensing object, turn the sensitivity adjuster clockwise until the indicator is turned ON by a background object, and define this posi- tion as (B). (3) Turn the sensitivity adjuster counterclockwise (decrease the sensitivity) from (B) until the indicator is turned OFF, and define this position. If the indicator is not turned ON by the background object at the maximum sensitivity, set the adjuster in the middle of (A) and maximum sensitivity. • The sensitivity adjuster may be damaged if an excessive force is applied.

Precautions

Correct Use

E3JK

Design

Power Reset Time

The Sensor is ready to detect an object within 200 ms after it is turned ON. If Sensor and load are connected to separate power supplies, ensure to turn ON the Sensor first.

Wiring Considerations

Connection/Wiring

If the DC transistor output type is used, the sum of load currents of L-ON output (NO) and D-ON output (NC) should be within 100 mA. If the sum of load currents exceeds 100 mA, the load short-circuit protection may be activated. (The load short-circuit protection is reset by turning OFF the power of the photoelectric sensor.)

Miscellaneous

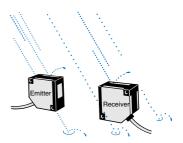
Ambient Conditions (Installation Area)

The E3JK will malfunction if installed in the following places.

- Places where the E3JK is exposed to a dusty environment.
- Places where corrosive gases are produced.

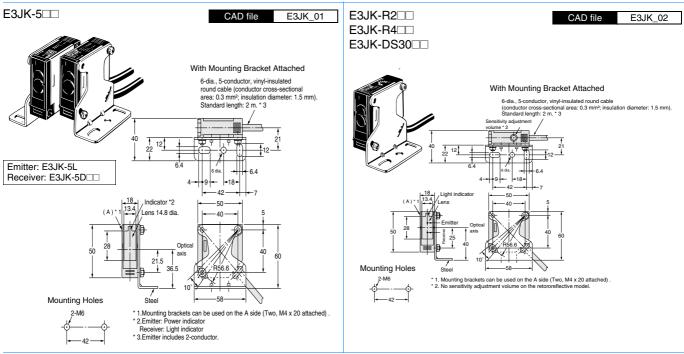


 Places where the E3JK is directly exposed to water, oil, or chemicals.



Dimensions (Unit: mm)

Sensors



Accessories (Order Separately)

